



0.5W, Bare Die Zener Diode

Rev 1.0
08/03/17

Silicon Planar Zener diode in bare die form – 5% tolerance, “C” grade

Features:

- High peak reverse power dissipation
- Sharp Reverse Characteristics
- Low Reverse Current Levels
- High Reliability Gold Back Metal
- High Reliability tested grades.

Ordering Information

The following part suffixes apply:

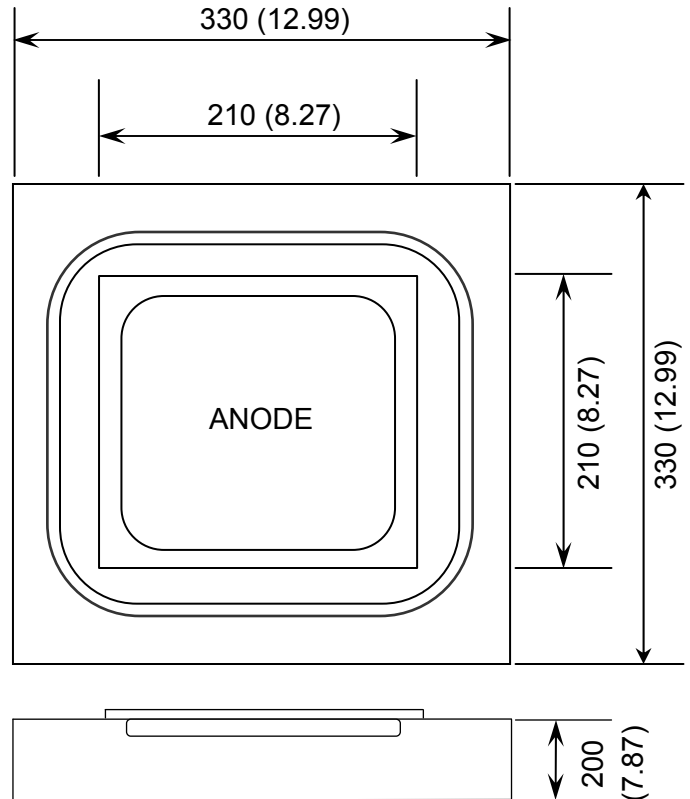
- No suffix - MIL-STD-750 /2073 Visual Inspection
- “H” - MIL-STD-750 /2073 Visual Inspection
+ MIL-PRF-38534 Class H LAT
- “K” - MIL-STD-750 /2073 Visual Inspection
+ MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com/quality/bare-die-lot-qualification

Die Dimensions in μm (mils)



Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – By specific request
- Unsawn Wafer – By specific request
- Tighter V_z tolerances:
2% - B grade, 1% - A grade – Specific request

Mechanical Specification

Die Size (Unsawn)	330 x 330 12.99 x 12.99	μm mils
Anode Pad Size	210 x 210 8.27 x 8.27	μm mils
Die Thickness	200 7.87	μm mils
Top Metal Composition	Al	
Back Metal Composition	Au	





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Absolute Maximum Ratings¹ $T_A = 25^\circ\text{C}$ unless otherwise stated

PARAMETER	SYMBOL	VALUE	UNIT
Power Dissipation ²	P_{TOT}	0.5	W
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_S	-65 to +1500	$^\circ\text{C}$
Forward Voltage @ $I_F = 10\text{mA}$	V_F	0.9	V

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise stated

DEVICE	ZENER VOLTAGE RANGE			TEST CURRENT		REVERSE LEAKAGE CURRENT		DYNAMIC RESISTANCE	
	$V_Z @ I_{ZT1}$			I_{ZT1}	I_{ZT2}	$I_R @ V_R$		$Z_Z @ I_{ZT1}$	$Z_{ZK} @ I_{ZT2}$
	V			mA		$\mu\text{A Max.}$	@ V_R	Ω	
	Min.	Nom	Max.					Max.	Max.
BZX84C2V4	2.2	2.4	2.6	5	0.25	100	1	100	1800
BZX84C2V7	2.5	2.7	2.9	5	0.25	75	1	100	1900
BZX84C3V0	2.8	3.0	3.2	5	0.25	50	1	95	2000
BZX84C3V3	3.1	3.3	3.5	5	0.25	25	1	95	2200
BZX84C3V6	3.4	3.6	3.8	5	0.25	15	1	90	2300
BZX84C3V9	3.7	3.9	4.1	5	0.25	10	1	90	2400
BZX84C4V3	4.0	4.3	4.6	5	0.25	5	1	88	2500
BZX84C4V7	4.4	4.7	5.0	5	0.25	3	1.5	70	2200
BZX84C5V1	4.8	5.1	5.4	5	0.25	2	2	50	2050
BZX84C5V6	5.2	5.6	6.0	5	0.25	2	3	25	1800
BZX84C6V2	5.8	6.2	6.6	5	0.25	1	4	10	1300
BZX84C6V8	6.4	6.8	7.2	5	0.25	1	5.2	8	750
BZX84C7V5	7.0	7.5	7.9	5	0.25	0.5	6	7	600
BZX84C8V2	7.7	8.2	8.7	5	0.25	0.5	6.5	7	600
BZX84C9V1	8.5	9.1	9.6	5	0.25	0.1	7	10	600

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

2. Assembled in TO-236 package. Performance in die form subject to assembly heat sinking and die attach methods.

Zener Voltages 10V to 75V are constructed using larger die geometry.

Please see [here](#) for further details

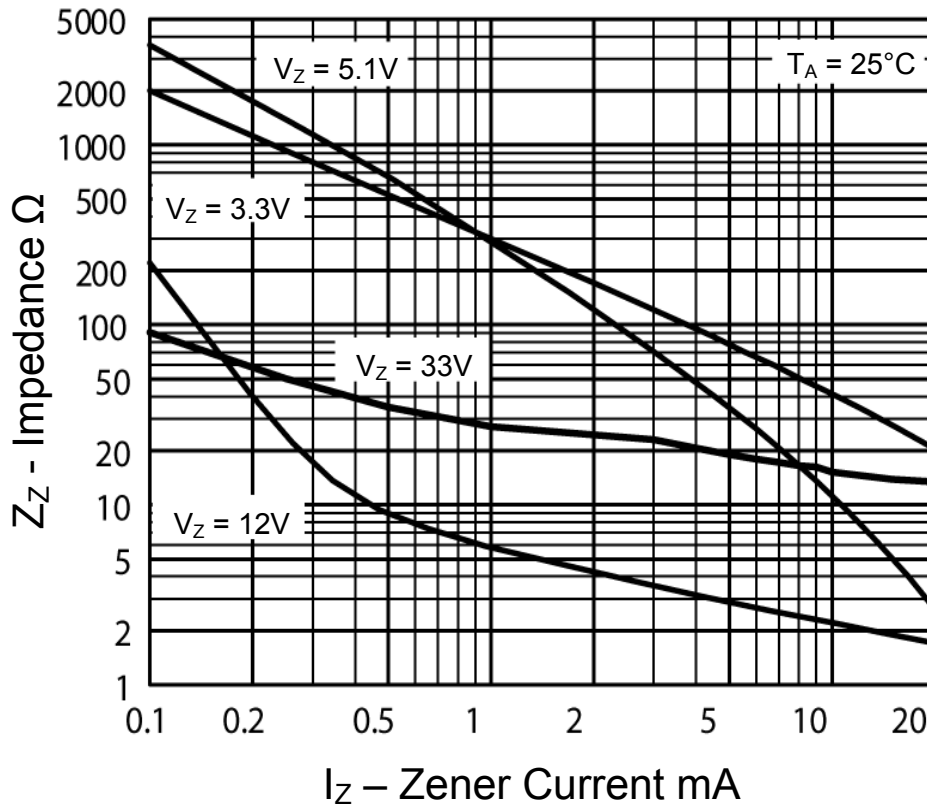




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Typical Electrical Characteristics



Zener Impedance Versus Operating Current - Z_Z Versus I_Z

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